

## CAN-Transceiver

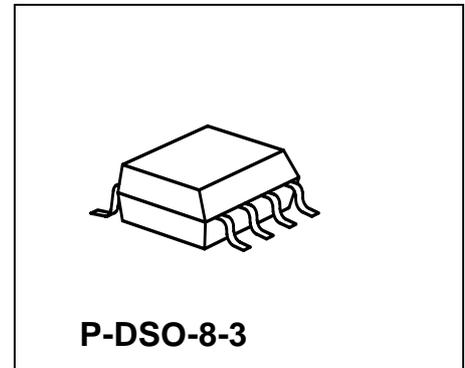
TLE 6250

### Target Data Sheet

#### 1 Overview

##### 1.1 Features

- CAN data transmission rate up to 1 Mbaud
- Compatible to ISO/DIS 11898
- Suitable for 12 V and 24 V applications
- Wide common mode range for immunity to EMI
- Version for 5V and 3.3V micro controllers
- No reverse currents from bus via an unpowered node
- Short circuit proof to ground and battery
- Overtemperatur protection



Type	Ordering Code	Package
TLE 6250 G	on request	P-DSO-8-3
TLE 6250 G V33	on request	P-DSO-8-3

#### Description

The CAN-transceiver TLE 6250 is a monolithic integrated circuit in a P-DSO-8-3 package for high speed differential mode data transmission in automotive and industrial applications. It works as an interface between the CAN protocol controller and the physical differential bus in both, 12 V and 24 V systems.

There are two versions available: one for 5 V logic and the other one for 3.3 V logic requiring additional supply via the  $V_{33V}$  pin. The IC can be set to stand-by mode via a control input.

The IC is based on the Siemens Power Technology SPT® which allows bipolar and CMOS control cricuity in accordance with DMOS power devices existing on the same monolithic circuitry.

The TLE 6250 is designed to withstand the severe conditions of automotive applications.

1.2 Pin Configuration (top view)

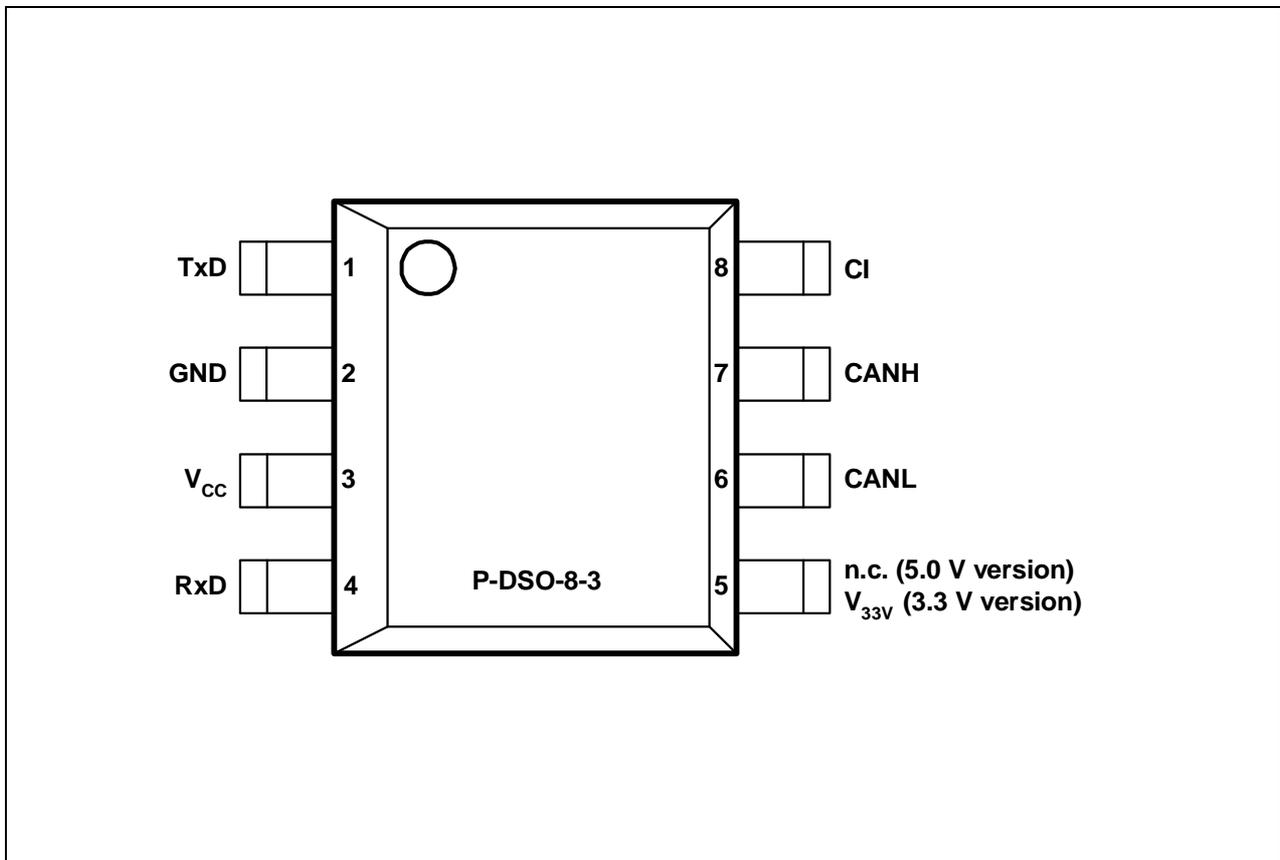


Figure 1

1.3 Pin Definitions and Functions

Pin No.	Symbol	Function
1	TxD	<b>CAN transmit data input</b> ; LOW in dominant state
2	GND	<b>Ground</b> ;
3	V <sub>CC</sub>	<b>5V Supply</b> ;
4	RxD	<b>CAN receive data output</b> ; LOW in dominant state, integrated pull up
5	n.c. V <sub>33V</sub>	<b>n.c.</b> ; not connected for 5.0 V version <b>3.3 V logic supply</b> ; (3.3 V version) for applications using 3.3 V microcontroller
6	CANL	<b>Low line input</b> ; LOW in dominant state
7	CANH	<b>High line output</b> ; HIGH in dominant state
8	CI	<b>Control input</b> ; set HIGH for stand-by mode

1.4 Functional Block Diagram

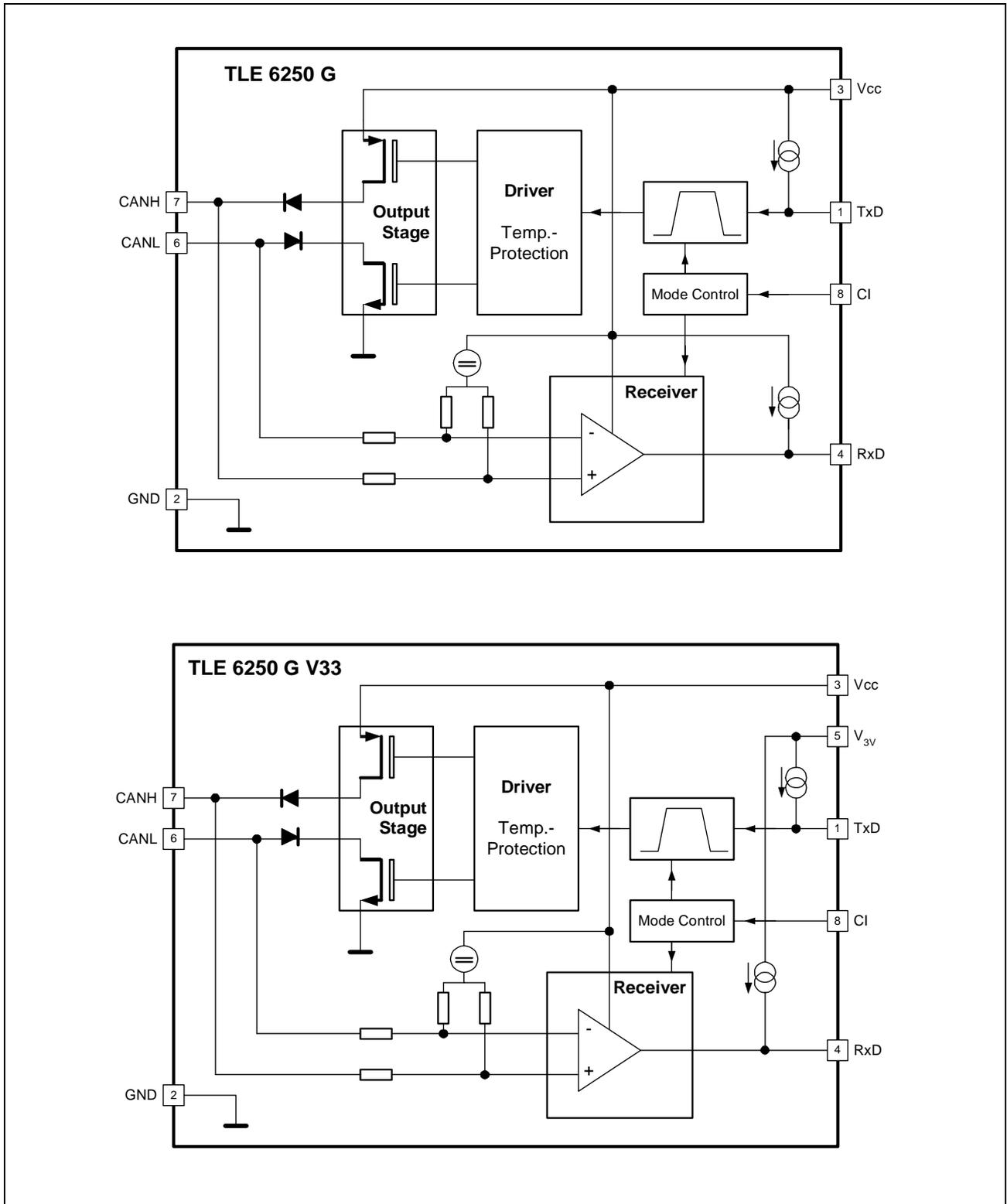


Figure 2

## 2 Electrical Characteristics

### 2.1 Absolute Maximum Ratings

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		

#### Voltages

Supply voltage	$V_{CC}$	-0.3	6	V	
3.3V supply	$V_{33V}$	-0.3	6	V	3.3 V version
CAN input voltage (CANH, CANL)	$V_{CANH/L}$	-20	40	V	
Logic voltages at CI, TxD, RxD	$V_I$	-0.3	$V_{CC} + 0.3$	V	$0\text{ V} < V_{CC} < 5.5\text{ V}$
Electrostatic discharge voltage	$V_{ESD}$	-2	2	kV	human body model (100 pF via 1.5 kΩ)

#### Currents


#### Temperatures

Junction temperature	$T_j$	-40	150	°C	–
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*Note: Maximum ratings are absolute ratings; exceeding any one of these values may cause irreversible damage to the integrated circuit.*

### 2.2 Operating Range

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		
Supply voltage	$V_{CC}$	4.5	5.5	V	
3V supply voltage	$V_{33V}$	3.0	3.6	V	3.3 V version
Junction temperature	$T_j$	- 40	150	°C	-

### Thermal Resistances

Junction ambient	$R_{thj-a}$	-	200	K/W	-
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## 2.3 Electrical Characteristics

4.5 V <  $V_{CC}$  < 5.5 V; (3.0 V <  $V_{33V}$  < 3.6 V for 3.3 V version);  $R_L = 60 \Omega$ ;  $V_{CI} > V_{CI,ON}$ ;  $-40^\circ\text{C} < T_j < 150^\circ\text{C}$ ; all voltages with respect to ground; positive current flowing into pin; unless otherwise specified.

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		

### Current Consumption

Current consumption	$I_{CC}$			15	mA	recessive state; $V_{TXD} = 4 \text{ V}$
Current consumption	$I_{CC}$			80	mA	dominant state; $V_{TXD} = 1 \text{ V}$
Current consumption	$I_{33V}$			2	mA	(3.3V version only)
Current consumption	$I_{CC,stab}$		200		$\mu\text{A}$	stand-by mode
Current consumption	$I_{CC+33V,stab}$		200		$\mu\text{A}$	stand-by mode (3.3V version only)

### Receiver Output RxD

HIGH level output voltage $V_{diff} = V_{CANH} - V_{CANL}$	$V_{OH}$	$0.8 \times V_{CC}$		$V_{CC}$	V	$I_{RX} = -300 \mu\text{A}$ ; $V_{diff} < 0,4 \text{ V}$
		$0.9 \times V_{33V}$		$V_{33V}$	V	3.3 V version $I_{RX} = -300 \mu\text{A}$ ; $V_{diff} < 0,4 \text{ V}$
LOW level output voltage $V_{diff} = V_{CANH} - V_{CANL}$	$V_{OL}$	0		$0.2 \times V_{CC}$	V	$I_{RX} = 1 \text{ mA}$ ; $V_{diff} > 1 \text{ V}$
		0		$0.2 \times V_{33V}$	V	3.3 V version $I_{RX} = 1 \text{ mA}$ ; $V_{diff} > 1 \text{ V}$

### Bus receiver

Differential receiver threshold voltage $V_{diff} = V_{CANH} - V_{CANL}$	$V_{diff}$	$0.1 \times V_{CC}$		$0.18 \times V_{CC}$	V	$-2 \text{ V} < (V_{CANH}, V_{CANL}) < 7 \text{ V}$
Differential receiver hysteresis	$V_{diff} \text{ (hys)}$		200		mV	
CANH, CANL input resistance	$R_i$		20		$\text{k}\Omega$	recessive state
Differential input resistance	$R_{diff}$		40		$\text{k}\Omega$	recessive state

## 2.3 Electrical Characteristics (cont'd)

$4.5\text{ V} < V_{CC} < 5.5\text{ V}$ ; ( $3.0\text{ V} < V_{33V} < 3.6\text{ V}$  for 3.3 V version);  $R_L = 60\ \Omega$ ;  $V_{CI} > V_{CI,ON}$ ;  
 $-40\text{ }^\circ\text{C} < T_j < 150\text{ }^\circ\text{C}$ ; all voltages with respect to ground; positive current flowing into pin; unless otherwise specified.

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		

### Transmission Input TxD

HIGH level input voltage threshold	$V_{IH}$	$0.7 \times V_{CC}$	–	$V_{CC} + 0.3$	V	recessive state; 5.0 V version
		$0.7 \times V_{33V}$	–	$V_{33V} + 0.3$	V	recessive state; 3.3 V version
LOW level input voltage threshold	$V_{IL}$	-0.3	–	$0.3 \times V_{CC}$	V	dominant state
		-0.3	–	$0.3 \times V_{33V}$	V	dominant state 3.3 V version
HIGH level input current	$I_{IH}$	-200		-30	$\mu\text{A}$	$V_{TxD} = 4\text{ V}$
LOW level input current	$I_{IL}$	-800		-100	$\mu\text{A}$	$V_{TxD} = 1\text{ V}$

### Bus transmitter

CANL/CANH recessive output voltage	$V_{CANL/H}$	$0.4 \times V_{CC}$		$0.6 \times V_{CC}$	V	$V_{TxD} = 4\text{ V}$ ;
CANH, CANL recessive output voltage difference $V_{bus\Delta} = V_{CANH} - V_{CANL}$	$V_{bus\Delta}$	-500		50	mV	$V_{TxD} = 4\text{ V}$ ;
CANL dominant output voltage	$V_{CANL}$			2.0	V	$V_{TxD} = 1\text{ V}$ ;
CANH dominant output voltage	$V_{CANH}$	3.0			V	$V_{TxD} = 1\text{ V}$ ; $4.75\text{ V} < V_{CC} < 5.5\text{ V}$
CANH, CANL dominant output voltage difference $V_{bus\Delta} = V_{CANH} - V_{CANL}$	$V_{bus\Delta}$	1.5		3.0	V	$V_{TxD} = 1\text{ V}$ ; $4.75\text{ V} < V_{CC} < 5.5\text{ V}$
CANL short circuit current	$I_{CANLsc}$		140		mA	$V_{CANLshort} = 18\text{ V}$
			180		mA	$V_{CANLshort} = 36\text{ V}$
CANH short circuit current	$I_{CANHsc}$		-140		mA	$V_{CANLshort} = -5\text{ V}$

### 2.3 Electrical Characteristics (cont'd)

4.5 V < V<sub>CC</sub> < 5.5 V; (3.0 V < V<sub>33V</sub> < 3.6 V for 3.3 V version); R<sub>L</sub> = 60 Ω; V<sub>CI</sub> > V<sub>CI,ON</sub>; -40 °C < T<sub>j</sub> < 150 °C; all voltages with respect to ground; positive current flowing into pin; unless otherwise specified.

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		
CANH leakage current	I <sub>CANHI</sub>	-10			μA	V <sub>CC</sub> = 0 V, -2 V < V <sub>CANH</sub> < 7 V, T <sub>j</sub> < 85 °C
CANL leakage current	I <sub>CANLI</sub>			10	μA	V <sub>CC</sub> = 0 V, -2 V < V <sub>CANL</sub> < 7 V, T <sub>j</sub> < 85 °C

### Mode control input (pin CI)

High input voltage	V <sub>CI,ON</sub>	0.75x V <sub>CC</sub>			V	stand-by mode
High input current	I <sub>CI,ON</sub>		5		μA	stand-by mode

### Dynamic CAN-Transceiver Characteristics

Propagation delay TxD-to-RxD LOW (recessive to dominant)	t <sub>d(L),TR</sub>		150	280	ns	C <sub>L</sub> = 47pF; R <sub>L</sub> = 60Ω; V <sub>CC</sub> = 5V; C <sub>RxD</sub> = 20pF
Propagation delay TxD-to-RxD HIGH (dominant to recessive)	t <sub>d(H),TR</sub>		150	280	ns	C <sub>L</sub> = 47 pF; R <sub>L</sub> = 60 Ω; V <sub>CC</sub> = 5 V; C <sub>RxD</sub> = 20pF
Propagation delay TxD LOW to bus dominant	t <sub>d(L),T</sub>		50		ns	C <sub>L</sub> = 47 pF; R <sub>L</sub> = 60 Ω; V <sub>CC</sub> = 5 V
Propagation delay TxD HIGH to bus recessive	t <sub>d(H),T</sub>		50		ns	C <sub>L</sub> = 47 pF; R <sub>L</sub> = 60 Ω; V <sub>CC</sub> = 5 V
Propagation delay bus dominant to RxD LOW	t <sub>d(L),R</sub>		100		ns	C <sub>L</sub> = 47 pF; R <sub>L</sub> = 60 Ω; V <sub>CC</sub> = 5V; C <sub>RxD</sub> = 20pF
Propagation delay bus recessive to RxD HIGH	t <sub>d(H),R</sub>		100		ns	C <sub>L</sub> = 47 pF; R <sub>L</sub> = 60 Ω; V <sub>CC</sub> = 5 V; C <sub>RxD</sub> = 20pF

### Thermal Shutdown (junction temperature)

Thermal shutdown temp.	T <sub>jSD</sub>	150	170	185	°C	-
Thermal shutdown hyst.	ΔT	-	10	-	K	-

3 Diagrams

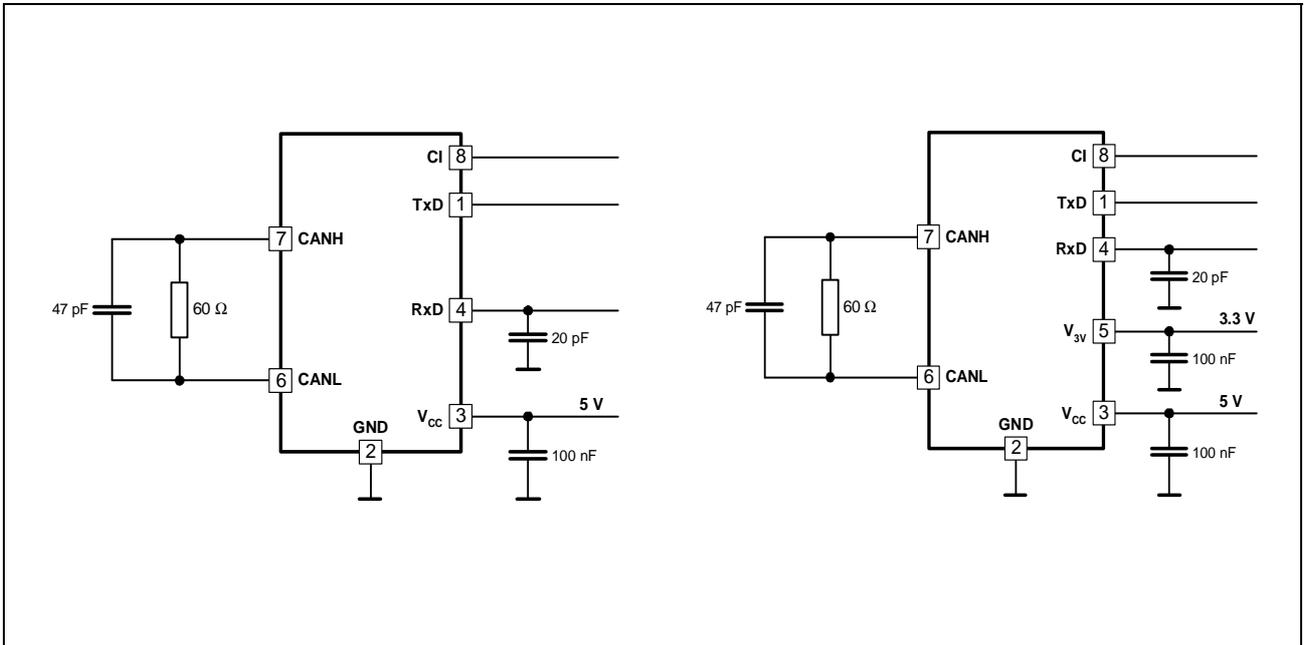


Figure 3: Test circuits

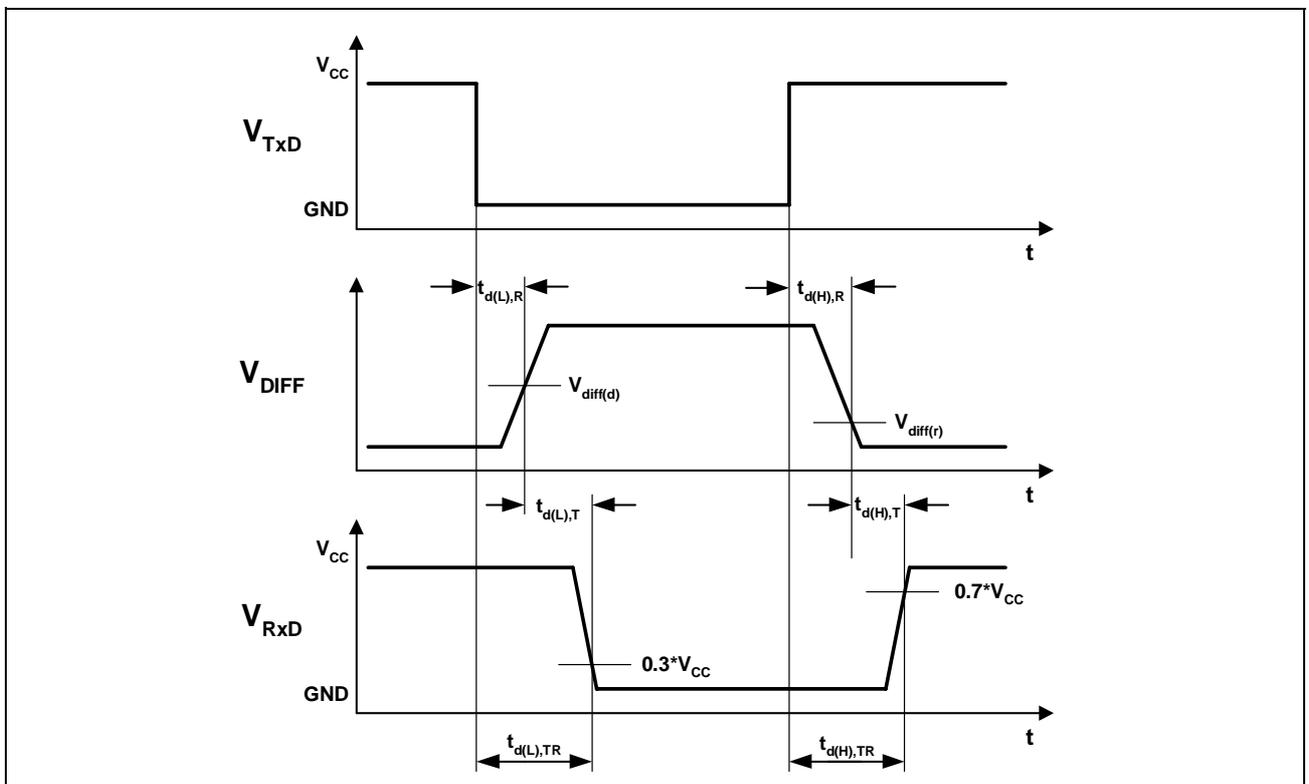


Figure 4: Timing diagrams for dynamic characteristics

4 Application

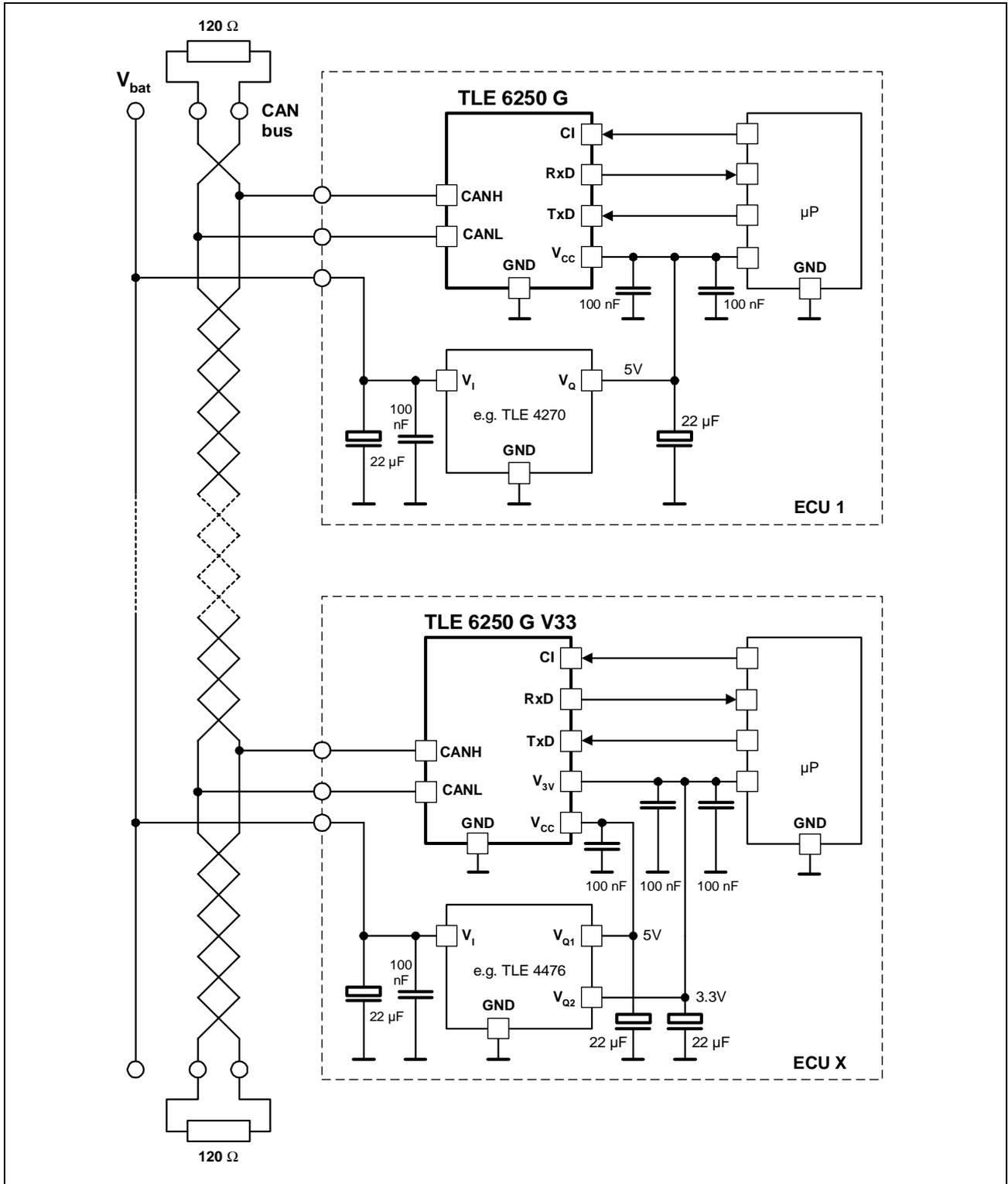
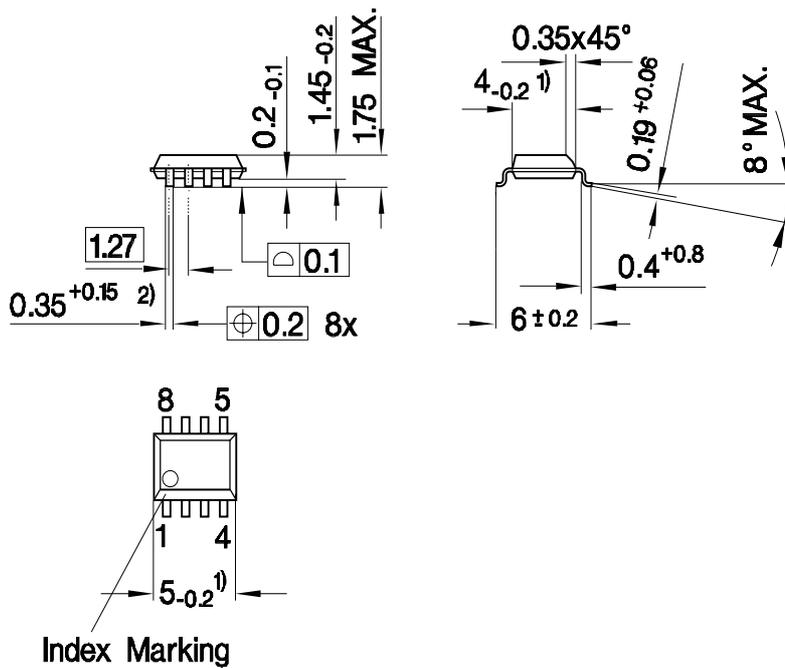


Figure 5  
Application Circuit

**5 Package Outlines**

**P-DSO-8-3**

(Plastic Dual Small Outline Package)



- 1) Does not include plastic or metal protrusion of 0.15 max. per side
- 2) Lead width can be 0.61 max. in dambar area

**Sorts of Packing**

Package outlines for tubes, trays etc. are contained in our Data Book "Package Information".

SMD = Surface Mounted Device

Dimensions in mm